

DATA SHEET

BLT81 UHF power transistor

Product specification
Supersedes data of November 1992

1996 May 09

UHF power transistor

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FEATURES

- SMD encapsulation
- Gold metallization ensures excellent reliability.

APPLICATIONS

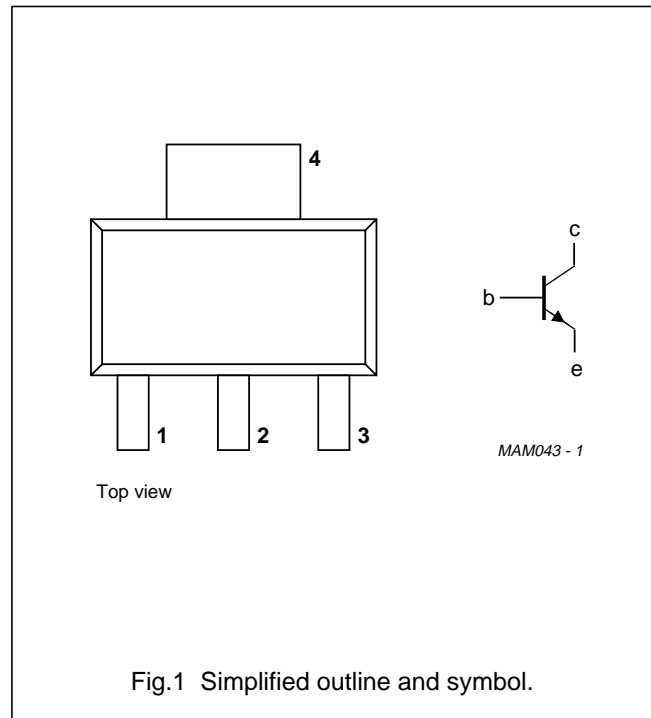
- Hand-held radio equipment in the 900 MHz communication band.

DESCRIPTION

NPN silicon planar epitaxial transistor encapsulated in a plastic SOT223 SMD package.

PINNING - SOT223

PIN	SYMBOL	DESCRIPTION
1	e	emitter
2	b	base
3	e	emitter
4	c	collector



QUICK REFERENCE DATA

RF performance at $T_s \leq 60 \text{ }^\circ\text{C}$ in a common emitter test circuit (see Fig.7).

MODE OF OPERATION	f (MHz)	V _{CE} (V)	P _L (W)	G _p (dB)	η_c (%)
CW, class-B narrow band	900	7.5	1.2	≥ 6	≥ 60
		6	1.2	typ. 6.5	typ. 77

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LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134).

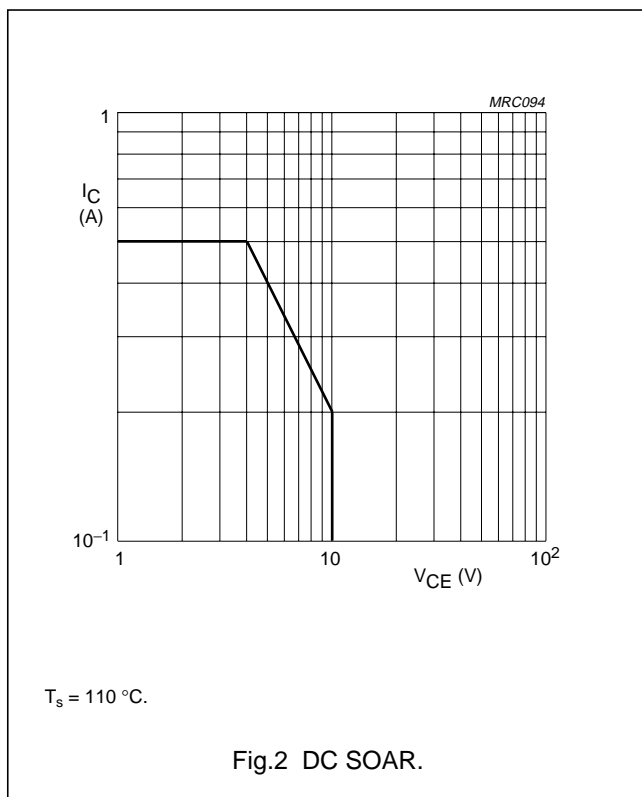
SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V_{CBO}	collector-base voltage	open emitter	–	20	V
V_{CEO}	collector-emitter voltage	open base	–	9.5	V
V_{EBO}	emitter-base voltage	open collector	–	2.5	V
I_C	collector current (DC)		–	500	mA
$I_{C(AV)}$	average collector current		–	500	mA
P_{tot}	total power dissipation	$T_s = 110\text{ °C}$; note 1	–	2	W
T_{stg}	storage temperature		–65	+150	°C
T_j	operating junction temperature		–	175	°C

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
$R_{th\ j-s}$	thermal resistance from junction to soldering point	$P_{tot} = 2\text{ W}$; $T_s = 110\text{ °C}$; note 1	32	K/W

Note to the “Limiting values” and “Thermal characteristics”

- T_s is the temperature at the soldering point of the collector pin.



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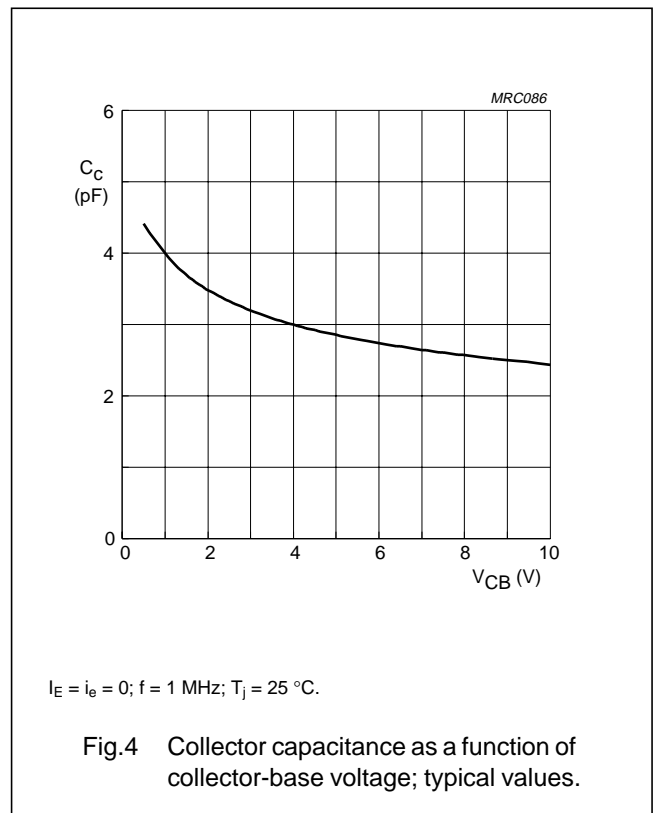
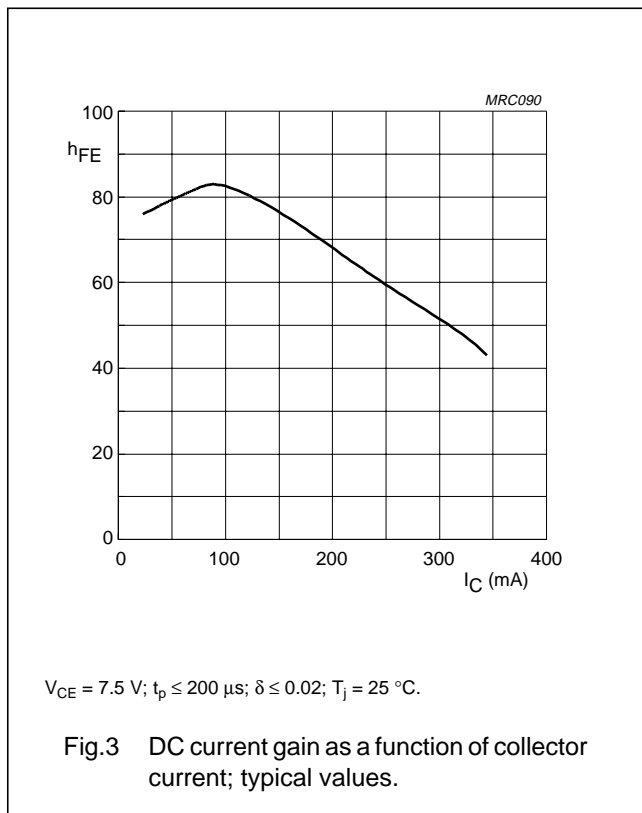
CHARACTERISTICS

$T_j = 25\text{ }^\circ\text{C}$ unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
$V_{(BR)CBO}$	collector-base breakdown voltage	open emitter; $I_C = 1\text{ mA}$	20	–	–	V
$V_{(BR)CEO}$	collector-emitter breakdown voltage	open base; $I_C = 10\text{ mA}$	9.5	–	–	V
$V_{(BR)EBO}$	emitter-base breakdown voltage	open collector; $I_E = 0.1\text{ mA}$	2.5	–	–	V
I_{CES}	collector leakage current	$V_{CE} = 10\text{ V}; V_{BE} = 0$	–	–	0.1	mA
h_{FE}	DC current gain	$V_{CE} = 5\text{ V}; I_C = 300\text{ mA}$; note 1;	25	–	–	
C_c	collector capacitance	$V_{CB} = 7.5\text{ V}; I_E = i_e = 0; f = 1\text{ MHz}$;	–	2.7	4	pF
C_{re}	feedback capacitance	$V_{CE} = 7.5\text{ V}; I_C = 0; f = 1\text{ MHz}$	–	1.7	3	pF

Note

1. Measured under pulsed conditions: $t_p \leq 200\text{ }\mu\text{s}$; $\delta \leq 0.02$.



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APPLICATION INFORMATION

RF performance at $T_s \leq 60\text{ }^\circ\text{C}$ in a common emitter test circuit (see note 1 and Fig.7).

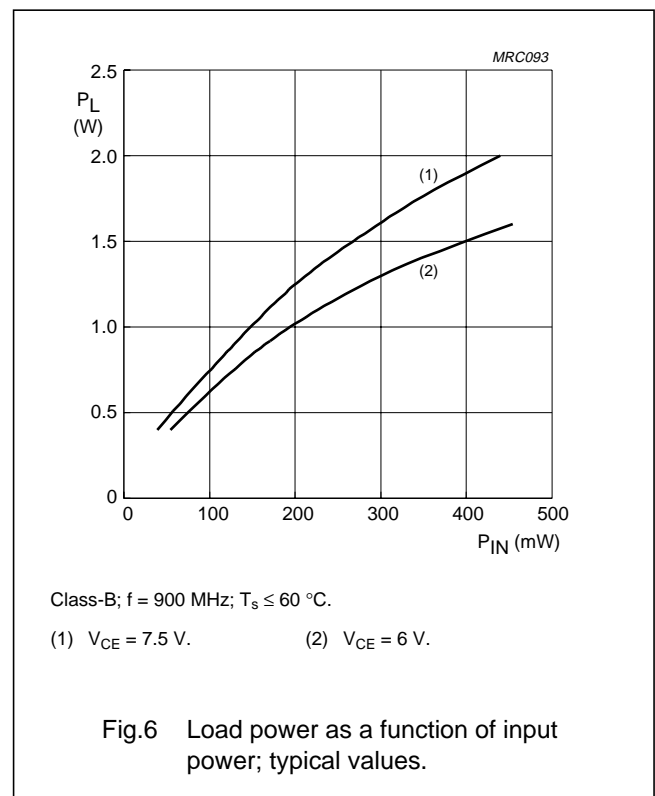
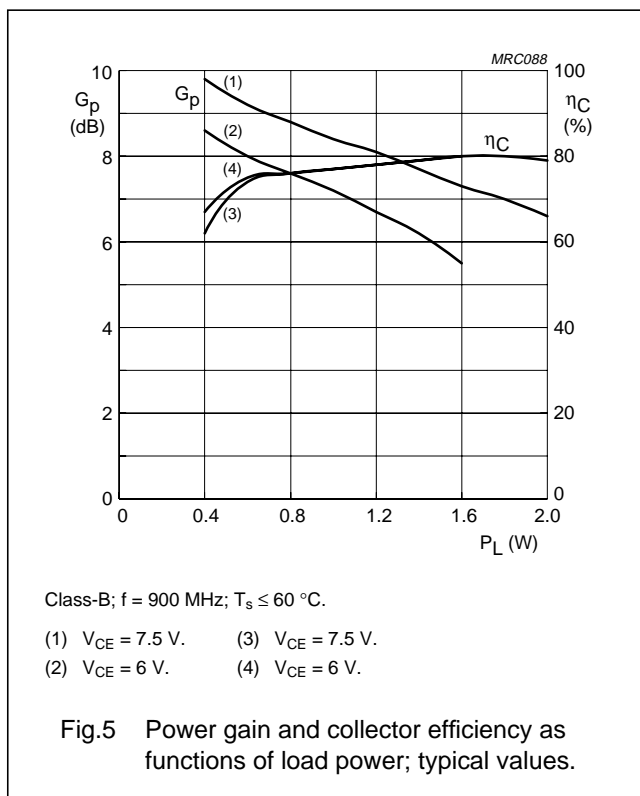
MODE OF OPERATION	f (MHz)	V _{CE} (V)	P _L (W)	G _p (dB)	η_c (%)
CW, class-B narrow band	900	7.5	1.2	≥ 6 typ. 8	≥ 60 typ. 77
		6	1.2	typ. 6.5	typ. 77

Note

- T_s is the temperature at the soldering point of the collector pin.

Ruggedness in class-AB operation

The BLT81 is capable of withstanding a load mismatch corresponding to VSWR = 50 : 1 through all phases under the following conditions: f = 900 MHz; V_{CE} = 9 V; P_L = 1.2 W; T_s ≤ 60 °C.



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Test circuit information

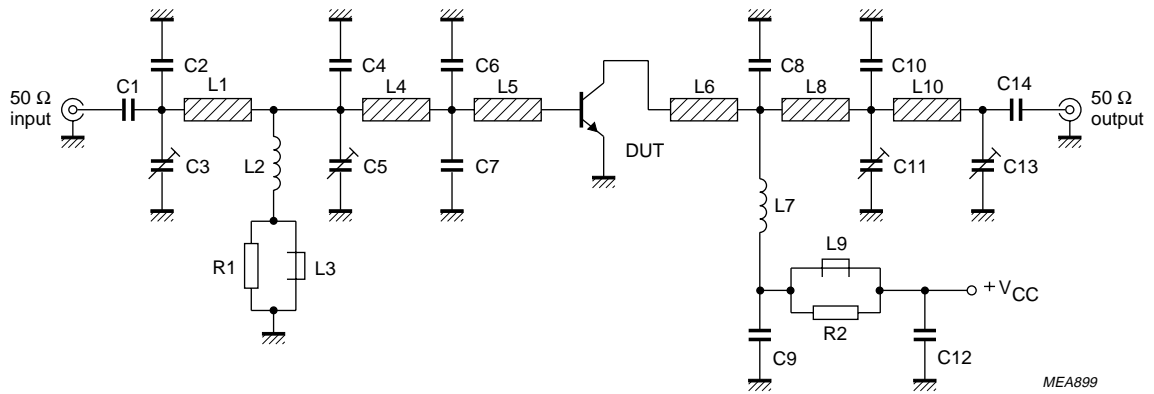


Fig.7 Common emitter test circuit for class-B operation at 900 MHz.

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List of components used in test circuit (see Figs 7 and 8)

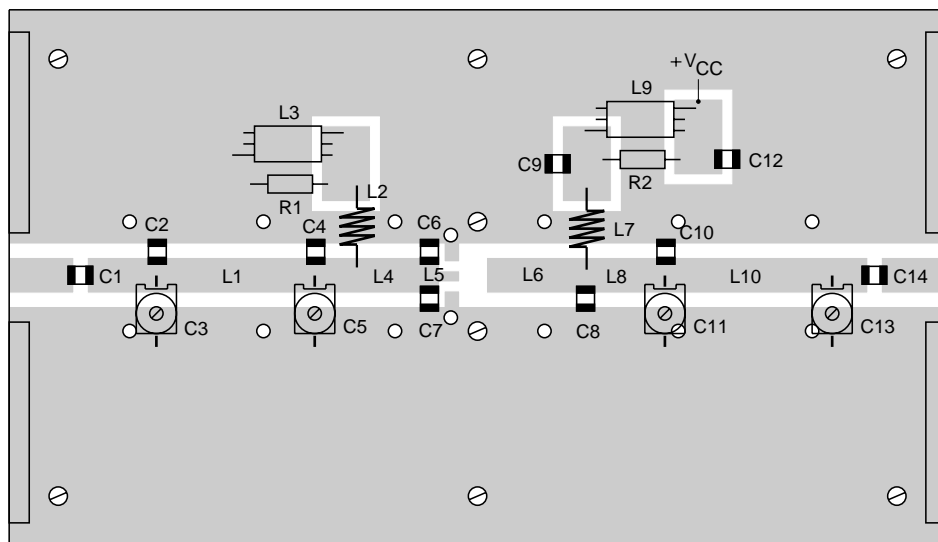
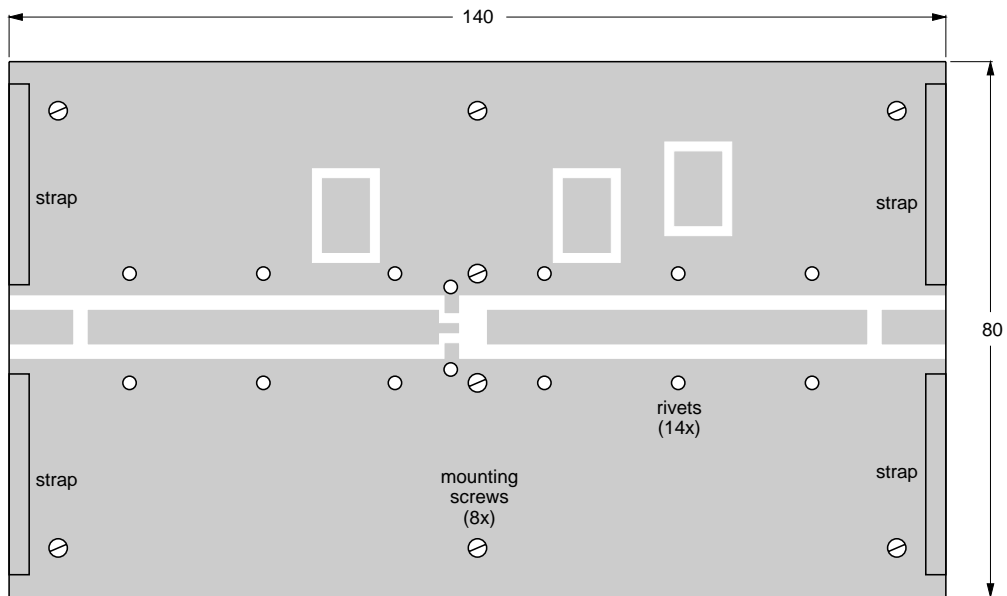
COMPONENT	DESCRIPTION	VALUE	DIMENSIONS	CATALOGUE No.
C1, C14	multilayer ceramic chip capacitor; note 1	100 pF		
C2	multilayer ceramic chip capacitor; note 1	3 pF		
C3, C5, C11, C13	film dielectric trimmer	1.4 to 5.5 pF		2222 809 09004
C4	multilayer ceramic chip capacitor; note 1	5.6 pF		
C6, C7, C10	multilayer ceramic chip capacitor; note 1	5.1 pF		
C8	multilayer ceramic chip capacitor; note 1	3.6 pF		
C9	multilayer ceramic chip capacitor; note 1	220 pF		
C12	multilayer ceramic chip capacitor;	1 nF		
L1	stripline; note 2	50 Ω	length 26.6 mm width 4.85 mm	
L2	10 turns enamelled 0.6 mm copper wire	250 nH	int. dia. 4.5 mm leads 2 \times 5 mm	
L3, L9	grade 3B Ferroxcube wideband HF choke			4312 020 36640
L4	stripline; note 2	50 Ω	length 18 mm width 4.85 mm	
L5	stripline; note 2	75 Ω	length 3.5 mm width 2.5 mm	
L6	stripline; note 2	50 Ω	length 10 mm width 4.85 mm	
L7	4 turns enamelled 0.6 mm copper wire	65 nH	int. dia. 4.5 mm leads 2 \times 5 mm	
L8	stripline; note 2	50 Ω	length 15 mm width 4.85 mm	
L10	stripline; note 2	50 Ω	length 24.6 mm width 4.85 mm	
R1, R2	metal film resistor	10 Ω , 0.25 W		

Notes

- American Technical Ceramics type 100B or capacitor of same quality.
- The striplines are on a double copper-clad printed-circuit board, with PTFE fibre-glass dielectric ($\epsilon_r = 2.2$); thickness $\frac{1}{16}$ " ; thickness of the copper sheet 35 μm .

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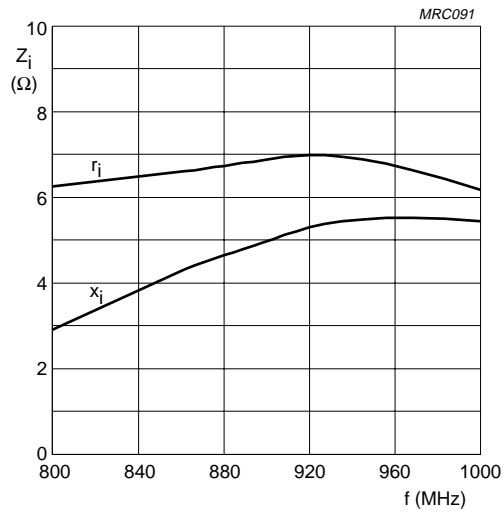
Dimensions in mm.

The components are situated on one side of the copper-clad PTFE fibre-glass board, the other side is unetched and serves as a ground plane. Earth connections from the component side to the ground plane are made by means of fixing screws and copper foil straps under the emitter leads.

Fig.8 Printed-circuit board and component lay-out for 900 MHz class-B test circuit in Fig.7.

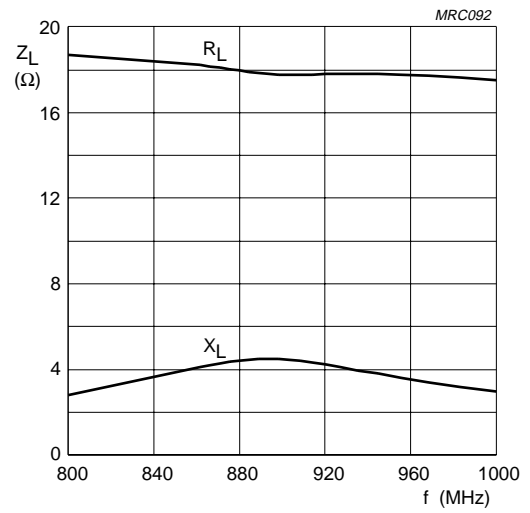
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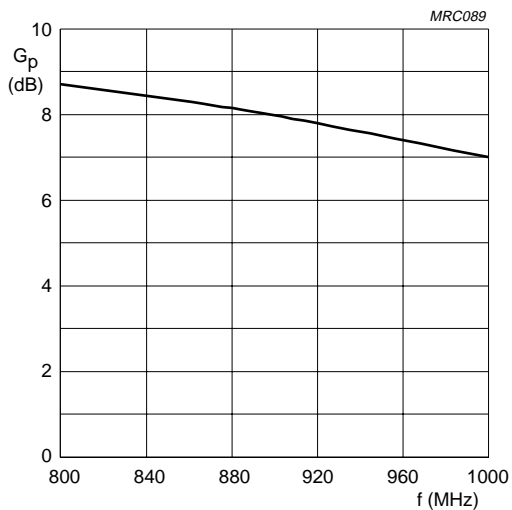
Class-B; $V_{CE} = 7.5$ V; $P_L = 1.2$ W; $T_s \leq 60$ °C.

Fig. 9 Input impedance as a function of frequency (series components); typical values.



Class-B; $V_{CE} = 7.5$ V; $P_L = 1.2$ W; $T_s \leq 60$ °C.

Fig. 10 Load impedance as a function of frequency (series components); typical values.



Class-B; $V_{CE} = 7.5$ V; $P_L = 1.2$ W; $T_s \leq 60$ °C.

Fig. 11 Power gain as a function of frequency; typical values.

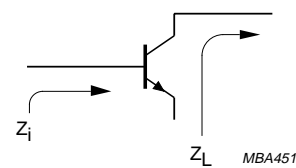
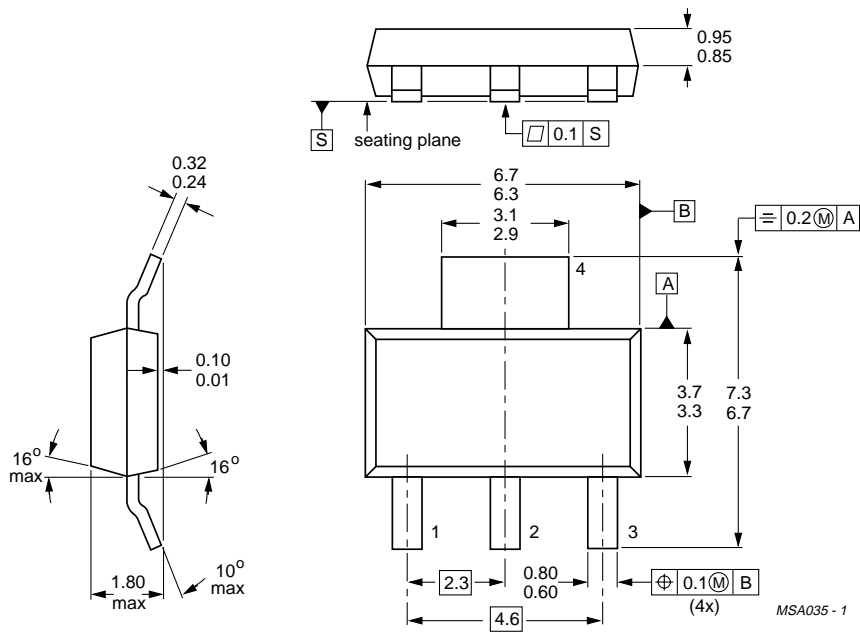


Fig. 12 Definition of transistor impedance.

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PACKAGE OUTLINE



Dimensions in mm.

Fig.13 SOT223.

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DEFINITIONS

Data Sheet Status	
Objective specification	This data sheet contains target or goal specifications for product development.
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.
Product specification	This data sheet contains final product specifications.
Limiting values	
Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.	
Application information	
Where application information is given, it is advisory and does not form part of the specification.	

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